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(54) Title: CONTROL OF MEMORY ACCESS OPERATIONS

(57) Abstract

Techniques (methods and devices) to control access to computer system memory are described. One technique limits memory access operations on receipt of a signal indicating, for example, a high temperature condition of a memory. The technique includes receiving a signal indicating that a temperature of the memory has exceeded a first specified value, blocking access to the memory during a first interval while the temperature continues to exceed the first specified value, and allowing access to the memory during a second interval while the temperature continues to exceed the first specified value.

